

GaAs MMIC SPDT NON-REFLECTIVE SWITCH. DC - 20 GHz

Typical Applications

This switch is suitable DC - 20 GHz applications:

- Fiber Optics
- Microwave Radio
- Military
- Space
- VSAT

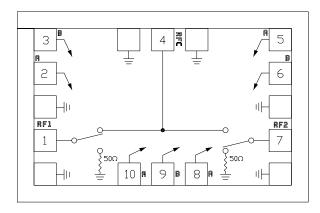
Features

High Isolation: >40 dB @ 20 GHz Low Insertion Loss: 1.6 dB @ 20 GHz

Non-Reflective Design

Small Size: 1.3 x 0.8 x 0.1 mm

Functional Diagram



General Description

The HMC347 is a broadband non-reflective GaAs MESFET SPDT MMIC chip. Covering DC to 20 GHz, the switch offers high isolation and low insertion loss. The switch features over 50 dB isolation at lower frequencies and over 40 dB at higher frequencies due to the implementation of on-chip via hole structures. The switch operates using two negative control voltage logic lines of -5/0V, requires no Vee and has no current consumption. The switch operates down to DC. The chip features coplanar I/Os that allow 100% RF testing prior to delivery to the customer.

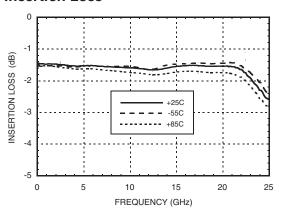
Electrical Specifications, $T_A = +25^{\circ}$ C, With 0/-5V Control, 50 Ohm System

Parameter		Frequency	Min.	Тур.	Max.	Units
Insertion Loss		DC - 20.0 GHz		1.7	2.2	dB
Isolation		DC - 20.0 GHz	40	45		dB
Return Loss	"On State"	DC - 20.0 GHz	10	13		dB
Return Loss RF1, RF2	"On State"	DC - 20.0 GHz	8	10		dB
Input Power for 1 dB Compression		0.5 - 20.0 GHz	19	23		dBm
Input Third Order Intercept		0.5 - 20.0 GHz	38	43		dBm
Switching Characteristics tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)		DC - 20.0 GHz		3 6		ns ns

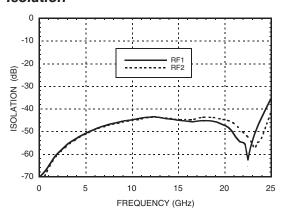


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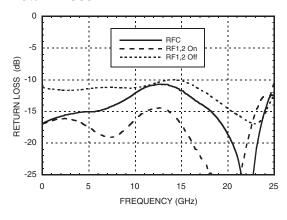
Insertion Loss



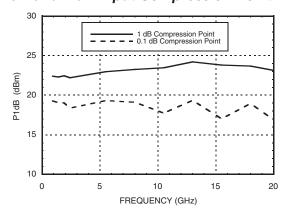
Isolation



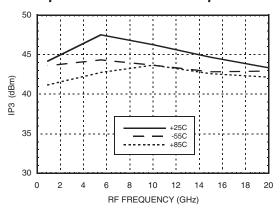
Return Loss



0.1 and 1 dB Input Compression Point



Input Third Order Intercept Point





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Absolute Maximum Ratings

RF Input Power (Vctl = -5V)	+27 dBm
Control Voltage Range (A & B)	+0.5V to -7.5 Vdc
Channel Temperature	150 °C
Thermal Resistance (Insertion Loss Path)	440 °C/W
Thermal Resistance (Terminated Path)	540 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C
ESD Sensitivity (HBM)	Class 1A

Control Voltages

State	Bias Condition	
Low	0 to -0.2V @ 10 uA Max.	
High	-5V @ 10 uA Typ. to -7V @ 40 uA Max.	

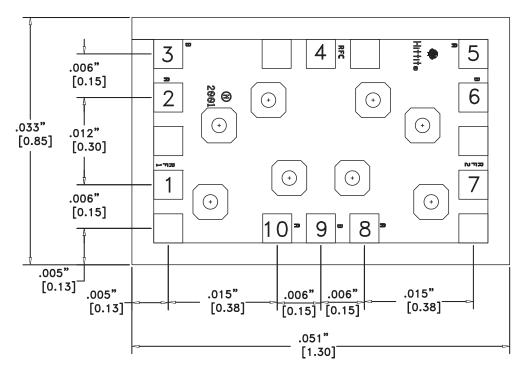
Truth Table

Control Input		Signal Path State		
Α	В	RFC to RF1	RFC to RF2	
High	Low	ON	OFF	
Low	High	OFF	ON	



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Outline Drawing



Die Packaging Information [1]

Standard		Alternate	
	WP-8 (Waffle Pack)	[2]	

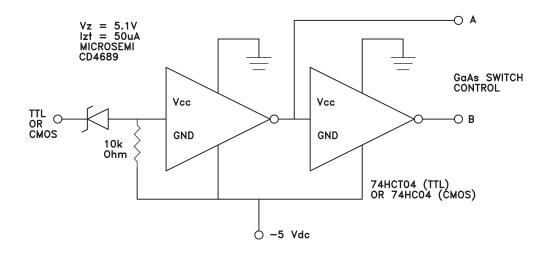
[1] Refer to the "Packaging Information" section for die packaging dimensions.

[2] For alternate packaging information contact Hittite Microwave Corporation.



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Suggested Driver Circuit



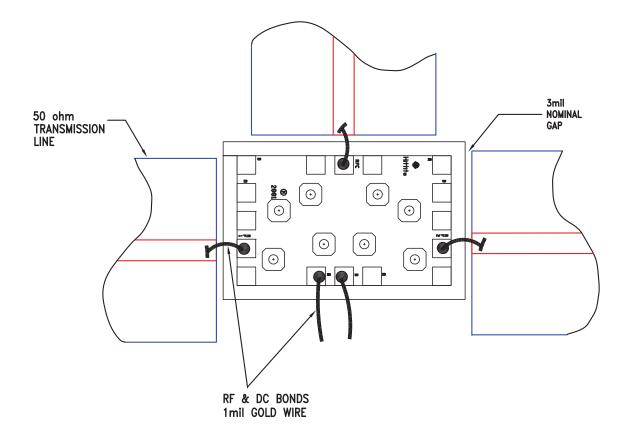
Pad Descriptions

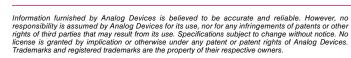
Pad Number	Function	Description	Interface Schematic
1, 4, 7	RFC, RF1, RF2	This pad is DC coupled and matched to 50 Ohm. Blocking capacitors are required if the RF line potential is not equal to 0V.	
2, 5, 8, 10	CTRLA	See truth table and control voltage table.	R
3, 6, 9	CTRLB	See truth table and control voltage table.	c
	GND	Die bottom must be connected to RF ground.	GND



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Assembly Diagram







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Mounting & Bonding Techniques for Millimeterwave GaAs MMICs

The die should be attached directly to the ground plane eutectically or with conductive epoxy (see HMC general Handling, Mounting, Bonding Note).

50 Ohm Microstrip transmission lines on 0.127mm (5 mil) thick alumina thin film substrates are recommended for bringing RF to and from the chip (Figure 1). If 0.254mm (10 mil) thick alumina thin film substrates must be used, the die should be raised 0.150mm (6 mils) so that the surface of the die is coplanar with the surface of the substrate. One way to accomplish this is to attach the 0.102mm (4 mil) thick die to a 0.150mm (6 mil) thick molybdenum heat spreader (moly-tab) which is then attached to the ground plane (Figure 2).

Microstrip substrates should be brought as close to the die as possible in order to minimize bond wire length. Typical die-to-substrate spacing is 0.076mm (3 mils).

Handling Precautions

Follow these precautions to avoid permanent damage.

Storage: All bare die are placed in either Waffle or Gel based ESD protective containers, and then sealed in an ESD protective bag for shipment. Once the sealed ESD protective bag has been opened, all die should be stored in a dry nitrogen environment.

Cleanliness: Handle the chips in a clean environment. DO NOT attempt to clean the chip using liquid cleaning systems.

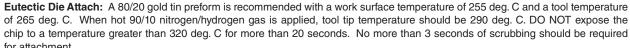
Static Sensitivity: Follow ESD precautions to protect against ESD strikes.

Transients: Suppress instrument and bias supply transients while bias is applied. Use shielded signal and bias cables to minimize inductive pick-up.

General Handling: Handle the chip along the edges with a vacuum collet or with a sharp pair of bent tweezers. The surface of the chip has fragile air bridges and should not be touched with vacuum collet, tweezers, or fingers.

Mounting

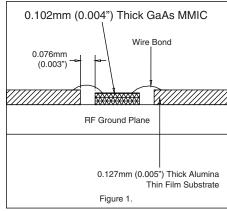
The chip is back-metallized and can be die mounted with AuSn eutectic preforms or with electrically conductive epoxy. The mounting surface should be clean and flat.

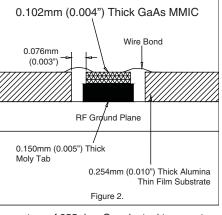


Epoxy Die Attach: Apply a minimum amount of epoxy to the mounting surface so that a thin epoxy fillet is observed around the perimeter of the chip once it is placed into position. Cure epoxy per the manufacturer's schedule.

Wire Bonding

Ball or wedge bond with 0.025 mm (1 mil) diameter pure gold wire (DC bias, IF1 and IF2) or Ribbon Bond (RF and LO ports) 0.076 mm x 0.013 mm (3 mil x 0.5 mil) size is recommended. Thermosonic wirebonding with a nominal stage temperature of 150 °C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Use the minimum level of ultrasonic energy to achieve reliable wirebonds. Wirebonds should be started on the chip and terminated on the package or substrate. All bonds should be as short as possible <0.31 mm (12 mils).





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Analog Devices Inc.: HMC347 HMC347-SX